Single Emitter Diode Lasers, 780-830 nm

High-Power Single Emitters for Pumping and Direct-Diode Applications



DEVICE SPECIFICATIONS 1,2	90-100 μm emitter width	
	1.6W 100 μm	3.2W 90 µm
Optical Output Power (W) (unlensed)	1.6	3.5
Optical Output Power (W) (lensed)	1.6	3.5
Emitter Width (µm)	100	100
Centroid Wavelength Available ³ (nm)	780 to 830	780 to 830
Centroid Wavelength, Standard (nm) (at 25°C)	808 ±3	808 ±3
Spectral Width, Standard (nm)	<3	<3
Wavelength Temperature Coefficient (nm/°C)	0.28	0.28
Polarization	TM	TE
Fast Axis Divergence (degrees) (unlensed) (FWHM)	31	29
Fast Axis Divergence (degrees) (lensed) (FWHM)	<4	<4
Slow Axis Divergence (degrees) (FWHM)	<10	<11
Threshold Current (A) (typical)	0.3	0.5
Operating Current (A)	<2.0 (1.7 typical)	<3.5 (3.0 typical)
Operating Voltage (V)	<2.0	<2.0
Operating Temperature ⁴ (°C)	25	25
Operating Temperature Range (°C)	15 to 40	15 to 40
Storage Temperature Range (°C)	-40 to +60	-40 to +60

¹ Specifications listed here apply at beginning of life. Operating current at end of life is 120% the operating current at beginning of life.

OPERATION NOTES:

ESD precautions must be taken when handling unit.

Negative current transients greater than 25 µA and/or reverse voltages >3V can destroy the unit.

Unit requires an adequate heat sink. Failure to supply an adequate heat sink will destroy the unit.

A dry environment should be provided when storing or operating a device with an open diode laser facet at temperatures below the ambient dew point. Failure to do so will cause condensation on the unit and can destroy it.



Please consult the factory for any requirements not listed, including the following options:
Centroid wavelength and spectral width requirements other than listed here.

⁻ Optical output powers other than listed here.

⁻ Emitter aperture widths other than listed here

³ Contact factory for availability.

⁴ Operating temperature is measured at the base of the package. The recommended operating temperature range is 15-40°C. Specifications listed here apply at 25°C.

DEVICE SPECIFICATIONS 1,2	140-150 μm emitter width	
	2.5W 150 μm	5W 140 μm
Optical Output Power (W) (unlensed)	2.5	5
Optical Output Power (W) (lensed)	2.5	5
Emitter Width (µm)	150	140
Centroid Wavelength Available ³ (nm)	780 to 830	780 to 830
Centroid Wavelength, Standard (nm) (at 25°C)	808 ±3	808 ±3
Spectral Width, Standard (nm)	<3	<3
Wavelength Temperature Coefficient (nm/°C)	0.28	0.28
Polarization	TM	TE
Fast Axis Divergence (degrees) (unlensed) (FWHM)	31	29
Fast Axis Divergence (degrees) (lensed) (FWHM)	<4	<4
Slow Axis Divergence (degrees) (FWHM)	<10	<11
Threshold Current (A) (typical)	0.5	0.8
Operating Current (A)	<3.0 (2.8 typical)	<5.5 (4.8 typical)
Operating Voltage (V)	<2.0	<2.0
Operating Temperature ⁴ (°C)	25	25
Operating Temperature Range (°C)	15 to 40	15 to 40
Storage Temperature Range (°C)	-40 to +60	-40 to +60

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OPERATION NOTES:

ESD precautions must be taken when handling unit.

Negative current transients greater than 25 μ A and/or reverse voltages >3V can destroy the unit.

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Centroid wavelength and spectral width requirements other than listed here.

Optical output powers other than listed here

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DEVICE SPECIFICATIONS ^{1,2}	200 μm emitter width	
	7W 200 μm	
Optical Output Power (W) (unlensed)	7	
Optical Output Power (W) (lensed)	7	
Emitter Width (µm)	200	
Centroid Wavelength Available ³ (nm)	780 to 830	
Centroid Wavelength, Standard (nm) (at 25°C)	808 ±3	
Spectral Width, Standard (nm)	<3	
Wavelength Temperature Coefficient (nm/°C)	0.28	
Polarization	TE	
Fast Axis Divergence (degrees) (unlensed) (FWHM)	29	
Fast Axis Divergence (degrees) (lensed) (FWHM)	<4	
Slow Axis Divergence (degrees) (FWHM)	<11	
Threshold Current (A) (typical)	1.1	
Operating Current (A)	<8.5 (8.0 typical)	
Operating Voltage (V)	<2.0	
Operating Temperature ⁴ (°C)	25	
Operating Temperature Range (°C)	15 to 40	
Storage Temperature Range (°C)	-40 to +60	

¹ Specifications listed here apply at beginning of life. Operating current at end of life is 120% the operating current at beginning of life.

OPERATION NOTES:

ESD precautions must be taken when handling unit.

Negative current transients greater than 25 μ A and/or reverse voltages >3V can destroy the unit.

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Centroid wavelength and spectral width requirements other than listed here.

Optical output powers other than listed here

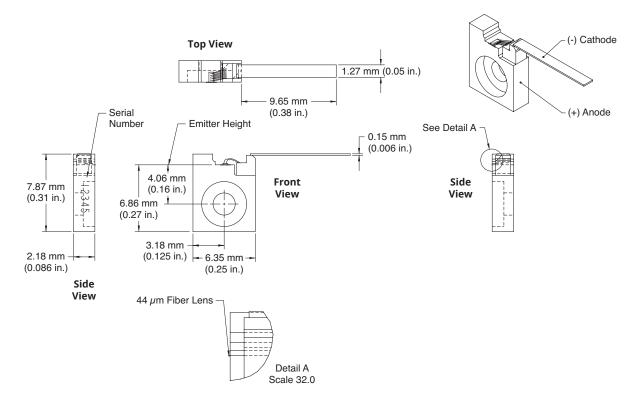
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MECHANICAL SPECIFICATIONS

780 nm to 830 nm Lensed C-Mount





Coherent, Inc., 5100 Patrick Henry Drive Santa Clara, CA 95054 p. (800) 527-3786 | (408) 764-4983 f. (408) 764-4646

tech.sales@coherent.com www.coherent.com